

Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene



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- The behavior of an electron is dependent on the behavior of the others
- Electron-electron correlations can induce spontaneous symmetry breaking



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Magic-angle twisted bilayer graphene





Magic-angle twisted bilayer graphene



Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene



Magic-angle twisted bilayer graphene



Are there similar correlated phases in natural bilayer graphene?



4. Correlated phases at electron-doping

Outline 2. Transport measurements bilayer graphene $I_{AC} = 1$ nA 3. Correlated phases at hole-doping kх 1. Bernal bilayer graphene kγ kx

17.05.2024

Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene



4. Correlated phases at electron-doping

Outline 2. Transport measurements graphene $I_{AC} = 1$ nA 3. Correlated phases at hole-doping 1. Bernal bilayer graphene kν

Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene



Bernal bilayer graphene



• Sublattice A and B



Bernal bilayer graphene





Bernal bilayer graphene



Parabolic band structure!

consistent with

K. S. Novoselov et al. *Nature Physics* 2, 177-180 (2006)
R. T. Weitz et al. *Science* 330, 812-816 (2010)
J. I. A. Li et al. *Science* 358, 648-652 (2017)
F. R. Geisenhof et al. *Nature* 598, 53-58 (2021)
and many others...



<u>A. M. Seiler</u>, N. Jacobsen, M. Statz, N. Fernandez, F. Falorsi, K. Watanabe, T. Taniguchi, Z. Dong, L. S. Levitov and R. T. Weitz, *Nat. Commun.* **15**, 3133 (2024)



Band structure calculations done by Nils Jacobsen



- Sublattice A and B
- 4-fold degeneracy: valley and spin degrees of freedom



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K/ K'

Bernal bilayer graphene



Electric displacement field *D*

breaks inversion symmetry

- Sublattice A and B
- 4-fold degeneracy: valley and spin degrees of freedom



see also:

E. McCann and V. I. Fal'ko. *PRL* **96**, 086805 (2006) and others A. Varlet et al. *PRL* **113**, 116602 (2014)





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Band structure calculations done by Nils Jacobsen





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4. Correlated phases at electron-doping

Outline 2. Transport measurements bilayer graphene $I_{AC} = 1$ nA 3. Correlated phases at hole-doping 1. Bernal bilayer graphene kv

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Fabrication of bilayer graphene heterostructures



hexagonal boron nitride (hBN)













Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene







Electrical transport measurements $-D = 0 \text{ Vnm}^{-1}$ $-D = 0.04 \text{ Vnm}^{-1}$ G (a.u.) bilayer 0.5 $V_{\rm f}$ graphene 0 0.04 Charge carrier $V_{\rm h}$ V nm⁻¹) density $I_{AC} = 1 n A$ ~ Fermi energy

$$\begin{array}{c} R = V/I_{AC} \\ G = 1/R \end{array} \qquad \begin{array}{c} n \sim V_{\rm t} + V_{\rm b} \\ D \sim V_{\rm t} - V_{\rm b} \end{array} \qquad \begin{array}{c} {\rm Electric} \\ {\rm displacement} \\ {\rm field} \end{array} \qquad \begin{array}{c} 0.02 \\ 0.00 \\ -1 \end{array} \qquad \begin{array}{c} 0.00 \\ -1 \end{array} \qquad \begin{array}{c} 0.00 \\ -1 \end{array} \qquad \begin{array}{c} 0.00 \\ 0.05 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \end{array} \qquad \begin{array}{c} 0 \\ 0 \\ 0 \end{array} \end{array}$$

Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene

G (a



4. Correlated phases at electron-doping

Outline 2. Transport measurements graphene 3. Correlated phases at hole-doping 1. Bernal bilayer graphene kv kx

Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene























Correlated phases in hole-doped bilayer graphene



 4x degenerate/ non-polarized phase -> full metal







- 4x degenerate/ non-polarized phase -> full metal
- Spin (s) polarized phase -> Stoner half metal







- 4x degenerate/ non-polarized phase -> full metal
- Spin (s) polarized phase -> Stoner half metal
- Spin (s) and valley (v) polarized phase -> Stoner quarter metal





Correlated phases in hole-doped bilayer graphene



- 4x degenerate/ non-polarized phase -> full metal
- Spin (s) polarized phase -> Stoner half metal
- Spin (s) and valley (v) polarized phase -> Stoner quarter metal

Consistent with

H. Zhou et al., *Science* **375**, 6582 (2022)
S. C. de la Barrera et al., *Nature Physics* **18**, 771-775 (2022)





Correlated phases beyond Stoner physics







Correlated phases beyond Stoner physics







Correlated phases beyond Stoner physics







Insulating phase at B = 0 T



- Non-linear bias-current dependence
- Insulating temperature dependence





Insulating phase at B = 0 T



- Non-linear
 Ir
 bias-current
 dependence
 d
- Insulating temperature dependence







Insulating phase at B = 0 T





- Non-linear bias-current dependence
- Insulating temperature dependence





Consistent with Wigner crystal





Applying an out-of-plane magnetic field







Applying an out-of-plane magnetic field



• Slope in the magnetic field (ν = -2)





Applying an out-of-plane magnetic field



- Slope in the magnetic field (ν = -2)
- Starts at finite density
- No moiré pattern



Applying an out-of-plane magnetic field



- Slope in the magnetic field (ν = -2)
- Starts at finite density
- No moiré pattern
 - Consistent with a Wigner Hall crystal

See also:

Z.Tešanović, Françoise Axel, and B. I.
Halperin, *Phys. Rev. B* 39, 8525 (1989)
J. Dong et al., arXiv:2311.05568 (2023)
B. Zhou et al., arXiv:2311.04217 (2023)
Z. Lu et al., *Nature* 626, 759–764 (2024)





Cascade of correlated phases



More correlated phases including:

- Correlated metals
- Topologically-trivial correlated insulator



4. Correlated phases at electron-doping



Correlated phases in the vicinity of tunable van Hove singularities in Bernal bilayer graphene





Trigonal warping in the conduction band







Trigonal warping in the conduction band







Trigonal warping in the conduction band





• Flat bands

- Van Hove singularity at the band edge
- High DOS























Insulating temperature dependence







Insulating temperature dependence



svi: spin and valley polarized (quasi-) insulator

si: spin polarized (quasi-) insulator

m: metal





Insulating temperature dependence



svi: spin and valley polarized (quasi-) insulator

si: spin polarized (quasi-) insulator

m: metal

Consistent with a charge density wave or Wigner crystal





Non-linear bias current







Non-linear bias current





Summary

Cascade of correlated phases in hole- and electron-doped bilayer graphene

- One correlated insulating state is consistent with a Wigner Hall crystal state
- Strong electron-hole asymmetry



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